

November 2013

FQD1N60C / FQU1N60C

N-Channel QFET[®] MOSFET 600 V, 1.0 A, 11.5 Ω

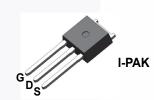
Features

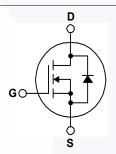
- 1 A, 600 V, $R_{DS(on)}$ = 11.5 Ω (Max.) @ V_{GS} = 10 V, I_{D} = 0.5 A
- Low Gate Charge (Typ. 4.8 nC)
- Low Crss (Typ. 3.5 pF)
- · 100% Avalanche Tested
- · RoHS Compliant

Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.







Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FQD1N60CTM / FQU1N60CTU	Unit
V _{DSS}	Drain-Source Voltage		600	V
	Drain Current - Continuous (T _C = 25°C)		1	Α
I _D	- Continuous (T _C = 100°C)		0.6	Α
I _{DM}	Drain Current - Pulsed	(Note 1)	4	Α
V _{GSS}	Gate-Source Voltage		± 30	V
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		33	mJ
I _{AR}	Avalanche Current (Note		1	Α
E _{AR}	Repetitive Avalanche Energy (Note 1)		2.8	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5	V/ns
	Power Dissipation (T _A = 25°C)*		2.5	W
P_{D}	Power Dissipation (T _C = 25°C)		28	W
	- Derate above 25°C		0.22	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C
T _L	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C

Thermal Characteristics

Symbol	Parameter	FQD1N60CTM / FQU1N60CTU	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max. 4.53		
В	Thermal Resistance, Junction-to-Ambient (minimum pad of 2 oz copper), Max.	110	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (* 1 in ² pad of 2 oz copper), Max.	50	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FQD1N60C	FQD1N60CTM	D-PAK	330mm	16mm	2500 units
FQU1N60C	FQU1N60CTU	I-PAK	Tube	N/A	70 units

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	600			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250 μA, Referenced to 25°C		0.6		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 600 V, V _{GS} = 0 V			1	μΑ
		V _{DS} = 480 V, T _C = 125°C			10	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -30 V, V _{DS} = 0 V			-100	nA
On Cha	racteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$	2.0		4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10 V, I _D = 0.5 A	\	2.8	3.4	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 40 V, I _D = 0.5 A		3.5		S
	ic Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$		130	170	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		19	25	pF
C _{rss}	Reverse Transfer Capacitance			3.5	4.5	pF
Switchi	ing Characteristics					
t _{d(on)}	Turn-On Delay Time	V _{DD} = 300 V, I _D = 1.1 A,		7	24	ns
t _r	Turn-On Rise Time	$R_G = 25 \Omega$		21	52	ns
t _{d(off)}	Turn-Off Delay Time			13	36	ns
t _f	Turn-Off Fall Time	(Note 4)	-	27	64	ns
Qg	Total Gate Charge	V _{DS} = 480 V, I _D = 1.1 A,	1	4.8	6.2	nC
Q_{gs}	Gate-Source Charge	V _{GS} = 10 V	-	0.7		nC
Q_{gd}	Gate-Drain Charge	(Note 4)	-	2.7		nC
Drain-S	Source Diode Characteristics ar	nd Maximum Ratings				
I _S	Maximum Continuous Drain-Source Diode Forward Current				1	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				4	Α
V_{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_S = 0.5 \text{ A}$			1.4	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = 1.1 A,		190		ns
Q _{rr}	Reverse Recovery Charge	dI _F / dt = 100 A/μs		0.53		μС

NOTES:

^{1.} Repetitive Rating : Pulse width limited by maximum junction temperature.

^{2.} L = 59 mH, I $_{AS}$ = $\,$ 1.1 A, V $_{DD}$ = 50 V, R $_{G}$ = 25 $\Omega,$ starting $\,$ T $_{J}$ = 25 $^{\circ}C.$

^{3.} $I_{SD} \le 1.1$ A, di/dt ≤ 200 A/ μ s, $V_{DD} \le BV_{DSS,}$ starting T_J = 25°C.

^{4.} Essentially independent of operating temperature.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

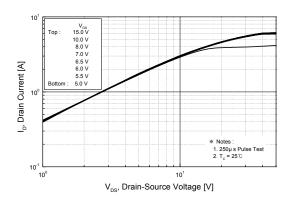


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

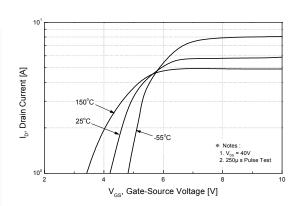


Figure 2. Transfer Characteristics

Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

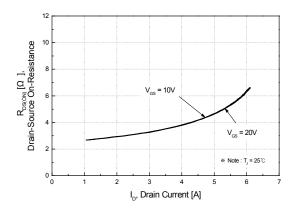


Figure 5. Capacitance Characteristics

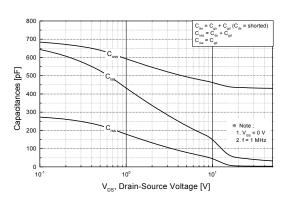
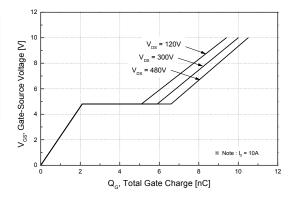


Figure 6. Gate Charge Characteristics



Typical Characteristics (Continued)

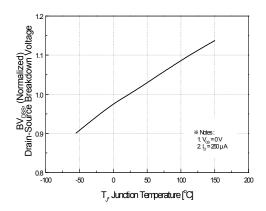


Figure 7. Breakdown Voltage Variation vs Temperature

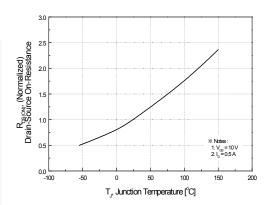


Figure 8. On-Resistance Variation vs Temperature

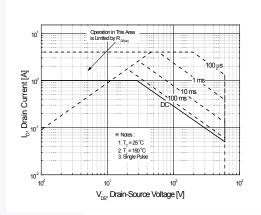


Figure 9. Maximum Safe Operating Area

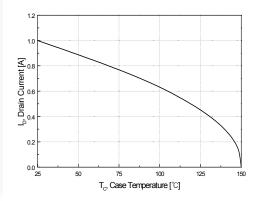


Figure 10. Maximum Drain Current vs Case Temperature

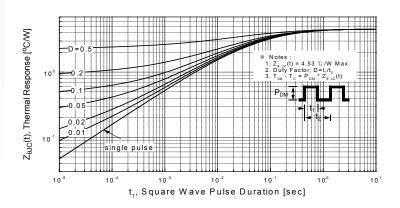


Figure 11. Transient Thermal Response Curve

Figure 12. Gate Charge Test Circuit & Waveform

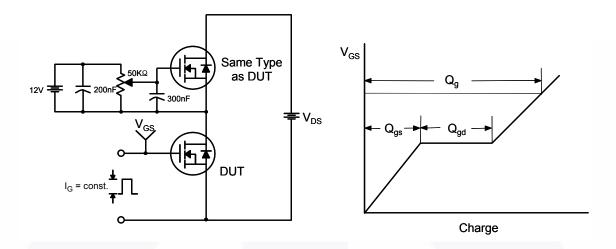


Figure 13. Resistive Switching Test Circuit & Waveforms

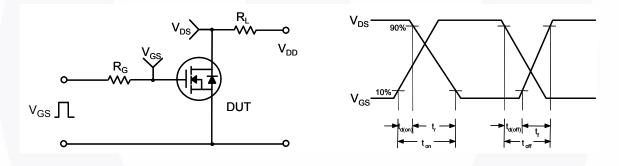
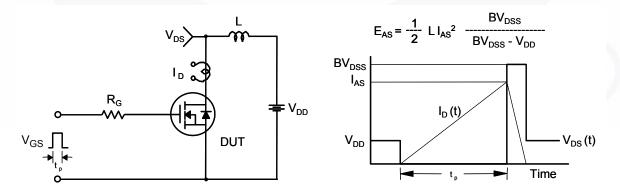


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



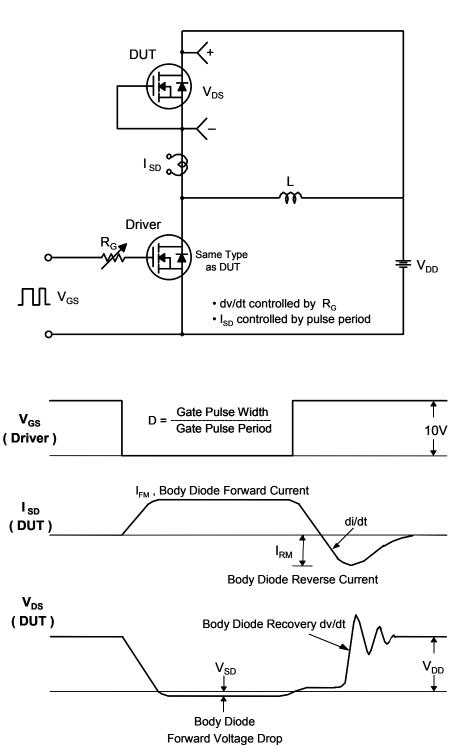


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

TO-252 3L (DPAK)

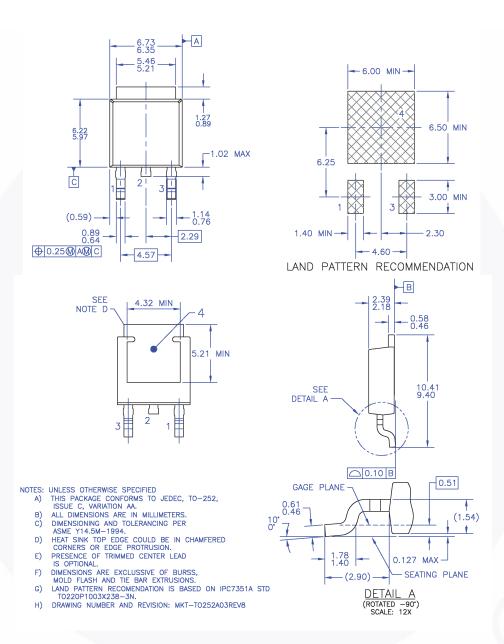


Figure 16. TO252 (D-PAK), Molded, 3 Lead, Option AA&AB

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Dimension in Millimeters

Mechanical Dimensions

TO-251 3L (IPAK)

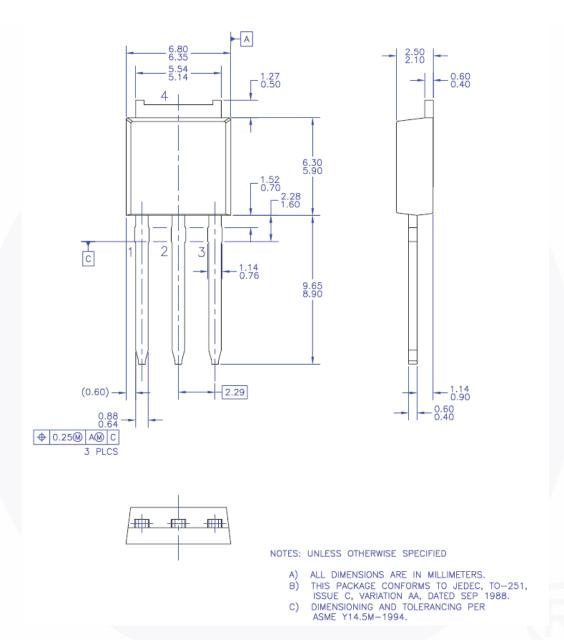


Figure 17. TO251 (IPAK) Molded 3 Lead

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Dimension in Millimeters





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